SPICE Device Model Si3437DV



Vishay Siliconix

P-Channel 150 V (D-S) MOSFET

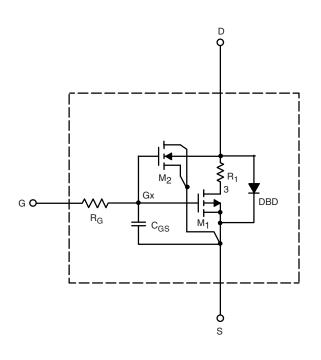
DESCRIPTION

The attached SPICE model describes the typical electrical characteristics of the p-channel vertical DMOS. The subcircuit model is extracted and optimized over the - 55 °C to + 125 °C temperature ranges under the pulsed 0 V to 5 V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage. A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched C_{gd} model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

SUBCIRCUIT MODEL SCHEMATIC

CHARACTERISTICS

- P-Channel Vertical DMOS
- Macro Model (Subcircuit Model)
- Level 3 MOS
- Apply for both Linear and Switching Application
- Accurate over the 55 °C to + 125 °C Temperature Range
- Model the Gate Charge, Transient, and Diode Reverse Recovery Characteristics



Note

 This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.

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SPECIFICATIONS (T _J = 25 °C, unless otherwise noted)					
PARAMETER	SYMBOL	TEST CONDITIONS	SIMULATED DATA	MEASURED DATA	UNIT
Static					
Gate-Source Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = -250 \ \mu A$	2.2	-	V
On-State Drain Current ^a	I _{D(on)}	$V_{DS} = -5 \text{ A}, V_{GS} = -10 \text{ V}$	16	-	А
Drain-Source On-State Resistance ^a	R _{DS(on)}	V_{GS} = - 10 V, I _D = - 1.4 A	0.60	0.61	Ω
		$V_{GS} = -6 V, I_D = -1 A$	0.64	0.64	
Forward Transconductance ^a	9 _{fs}	V _{DS} = - 10 V, I _D = - 1.4 A	1.6	4.5	S
Diode Forward Voltage	V _{SD}	$I_{\rm S} = -1$ A, $V_{\rm GS} = 0$ V	- 0.78	- 0.80	V
Dynamic ^b					
Input Capacitance	C _{iss}	V _{DS} = - 50 V, V _{GS} = 0 V, f = 1 MHz	646	510	pF
Output Capacitance	C _{oss}		30	30	
Reverse Transfer Capacitance	C _{rss}		15	21	
Total Gate Charge	Qg	$V_{DS} = -75 \text{ V}, V_{GS} = -10 \text{ V}, I_D = -1 \text{ A}$	9.4	12.2	nC
		V_{DS} = - 75 V, V_{GS} = - 6 V, I_{D} = - 1 A	6.4	8	
Gate-Source Charge	Q _{gs}		1.45	1.45	
Gate-Drain Charge	Q _{gd}		3.9	3.9	

Notes

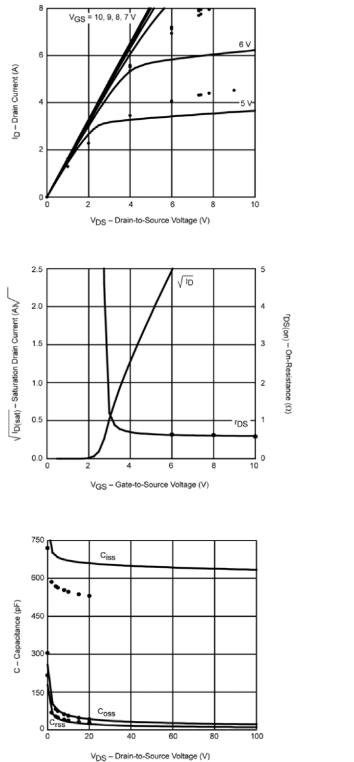
a. Pulse test; pulse width \leq 300 $\mu s,$ duty cycle \leq 2 %.

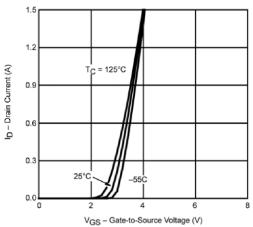
b. Guaranteed by design, not subject to production testing.

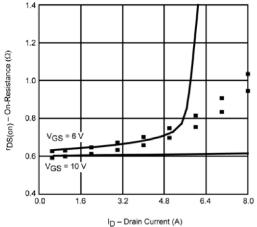


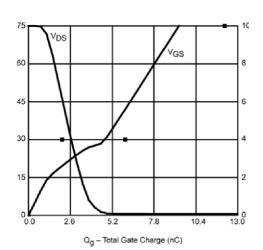
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COMPARISON OF MODEL WITH MEASURED DATA (T_J = 25 °C, unless otherwise noted)









Note

• Dots and squares represent measured data.

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